

2N4410

NPN SILICON TRANSISTOR



TO-92 CASE

**Central**  
Semiconductor Corp.

[www.centrasemi.com](http://www.centrasemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N4410 is a small signal NPN silicon transistor, manufactured by the epitaxial planar process, designed for general purpose amplifier applications.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	120	V
Collector-Emitter Voltage	$V_{CEO}$	80	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Collector Current	$I_C$	250	mA
Power Dissipation	$P_D$	625	mW
Operating and Storage Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\theta_{JA}$	200	$^\circ\text{C/W}$
Thermal Resistance	$\theta_{JC}$	83.3	$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

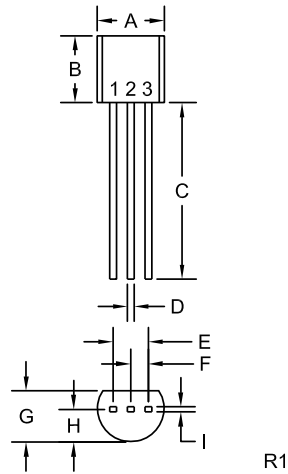
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$I_{CBO}$	$V_{CB}=100\text{V}$		10	nA
$I_{CBO}$	$V_{CB}=100\text{V}, T_A=100^\circ\text{C}$		1.0	$\mu\text{A}$
$I_{EBO}$	$V_{EB}=4.0\text{V}$		100	nA
$BV_{CBO}$	$I_C=10\mu\text{A}$	120		V
$BV_{CEX}$	$V_{BE}=5.0\text{V}, I_C=500\mu\text{A}, R_{BE}=8.2\text{k}\Omega$	120		V
$BV_{CEO}$	$I_C=1.0\text{mA}$	80		V
$BV_{EBO}$	$I_E=10\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=1.0\text{mA}, I_B=100\mu\text{A}$		200	mV
$V_{BE(SAT)}$	$I_C=1.0\text{mA}, I_B=100\mu\text{A}$		800	mV
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$		800	mV
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=1.0\text{mA}$	60		
$h_{FE}$	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	60	400	
$f_T$	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=20\text{MHz}$	60	300	MHz
$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		12	pF
$C_{ib}$	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$		50	pF

R0 (18-October 2010)

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**TO-92 CASE - MECHANICAL OUTLINE**



R1

**LEAD CODE:**

- 1) Emitter
- 2) Base
- 3) Collector

**MARKING:**

**FULL PART NUMBER**

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

R0 (18-October 2010)